

# 2SB1204/2SD1804

# **High-Current Switching Applications**

## **Applications**

· Relay drivers, high-speed inverters, converters, and other general high-current switching applications.

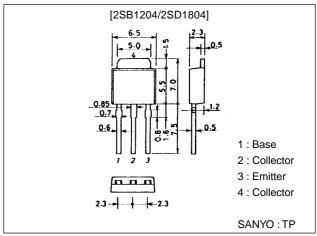
#### **Features**

- · Low collector-to-emitter saturation voltage.
- · High current and high f<sub>T</sub>.
- · Excellent linearity of hFF.
- · Fast switching time.
- · Small and slim package making it easy to make 2SB1204/2SD1804-applied sets smaller.

## **Package Dimensions**

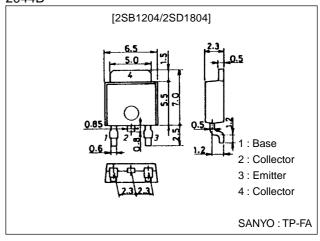
unit:mm

2045B



unit:mm

## 2044B



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### (): 2SB1204

# **Specifications**

## Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)60	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(-)50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)6	V
Collector Current	Ic		(-)8	Α
Collector Current (Pulse)	I <sub>CP</sub>		(–)12	Α
Collector Dissipation	PC		1	W
		Tc=25°C	20	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

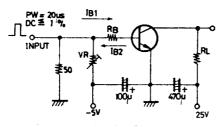
### **Electrical Characteristics at Ta = 25°C**

Parameter	Symbol	Conditions		11.7		
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(-)1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(–)1	μA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)0.5A	70*		400*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)6A	35			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)1A		(130)		MHz
				180		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(95)65		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)4A, I <sub>B</sub> =(-)0.2A		200	400	mV
				(-250)	(-500)	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)4A, I <sub>B</sub> =(-)0.2A		(-)0.95	(–)1.3	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0	(-)60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(-)50			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)10μA, I <sub>C</sub> =0	(-)6			V
Turn-ON Time	ton	See specified Test Circuit		(50)		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(450)		ns
				500		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		20		ns

 $<sup>\</sup>ast$  : The 2SB1204/2SD1804 are classified by 0.5A  $h_{FE}$  as follows :

	70	Q	140	100	R	200	140	S	280	200	Т	400
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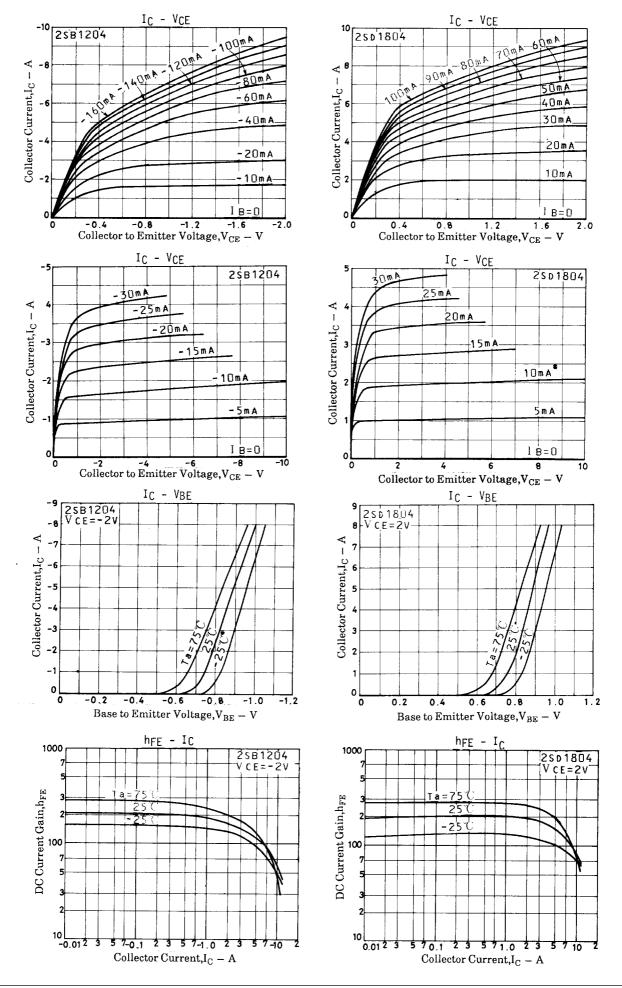
## **Switching Time Test Circuit**

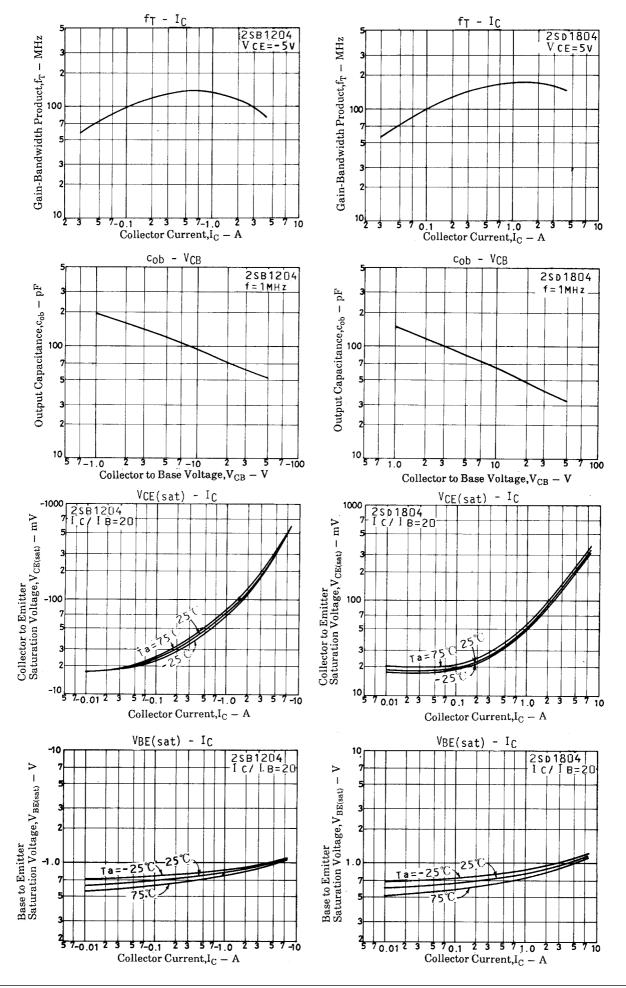


I C=10 I B1=-10 I B2=4A

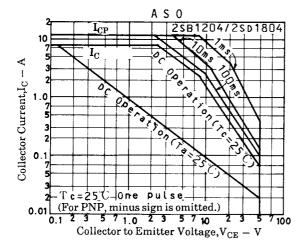
(For PNP, the polarity is reversed.)

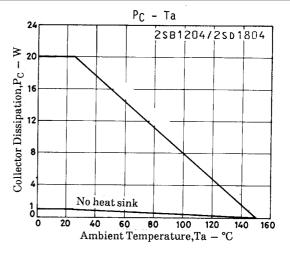
Unit (resistance :  $\Omega$ , capacitance : F)





#### 2SB1204/2SD1804





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